Customer No.: 31561 Application No.: 10/710,908 Docket No.: 11573-US-PA

## **AMENDMENTS**

## In The Claims

- 1. (currently amended) A chip structure, comprising:
- a chip, having an active surface and at least a bonding pad disposed on the active surface;
- a first passivation layer, disposed on the active surface, comprising at least a first opening exposing the bonding pad; and
  - a spacing pad, entirely disposed on the bonding pad within the first opening.
- 2. (original) The chip structure of claim 1, wherein the structure further comprises a metallic bump pad connected to the spacing pad and covering the peripheral surface around the first opening.
- 3. (original) The chip structure of claim 2, further comprising a second passivation layer disposed over the first passivation layer such that the second passivation layer comprises at least a second opening that exposes the metallic bump pad.
- 4. (original) The chip structure of claim 3, further comprising an under-bump metallic layer disposed on the top surface of the metallic bump pad and over the peripheral area around the second opening.
- 5. (original) The chip structure of claim 4, wherein further comprising a conductive bump connected to the under-bump metallic layer.
  - 6. (original) The chip structure of claim 3, further comprising a conductive bump connected

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to the metallic bump pad.

7. (original) The chip structure of claim 1, further comprising an under-bump metallic layer covering a top surface of the spacing pad and the peripheral area around the first opening.

8. (original) The chip structure of claim 7, further comprising a conductive bump connected to the under-bump metallic layer.

9. (currently amended) A conductive structure on the bonding pad of a chip having an active surface and at least a bonding pad disposed on the active surface, the conductive structure comprising:

a spacing pad, entirely disposed on and within the bonding pad, comprising a first surface and a corresponding second surface such that the first surface is in contact with the bonding pad;

a metallic bump pad, having a base in contact with the second surface of the spacing pad and a planar top surface; and

a conductive bump, having a base in contact with the planar top surface of the metallic bump pad.